

Form PTO-1449

U.S. DEPARTMENT OF COMMERCE  
PATENT AND TRADEMARK OFFICEATTY. DOCKET NO.  
**37392**SERIAL NO.  
**10/521,879**INFORMATION DISCLOSURE CITATION  
BY APPLICANT  
(USE SEVERAL SHEETS IF NECESSARY)APPLICANT:  
**Fabrice Pardo et al.**FILING DATE:  
**January 21, 2005**GROUP ART UNIT:  
**2814**

## U.S. PATENT DOCUMENTS

Examiner Initial		Document No.	Date	Name	Class	Subclass	Filing Date if Appropriate
JCI	A	5,227,648	07/1993	Woo			
JCI	B	5,663,639	09/1997	Brown et al.			
	C						
	D						
	E						

## FOREIGN PATENT DOCUMENTS

		Document No.	Date	Country	Class	Subclass	Translation
JCI	F	0 651 448 A1	03/1995	European			Corresponds to U.S. Patent No.: 5,512,763
	<del>G</del>	<del>2 805 950</del>	<del>07/2001</del>	<del>France</del>			Corresponds to U.S. Publication No.: 2003/010979
	H						

## OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, Etc.)

JCI	I	Katsumi Kishino et al., "Resonant Cavity-Enhanced (RCE) Photodetectors, August 8, 2001, pages 2025 - 2034,					
JCI	J	Wolfgang Kowalsky et al., "High Bandwidth Metal-Semiconductor-Metal Photodiodes with Integrated Fabry-Perot Resonator for WDM Receivers", August 1992, Pages 214 - 216					
JCI	K	A. Strittmatter et al., "High-Speed, High Efficiency Resonant-Cavity Enhanced InGaAs MSM Photodetectors", Pages 1231- 1232					
JCI	L	A. Strittmatter et al., "High-Frequency , Long-Wavelength Resonant-Cavity-Enhanced InGaAs MSM Photodetectors", September 15, 1996, Pages 145 - 148					

Examiner: **/John Ingham/**Date Considered **08/14/2006**

\*Examiner:

Initial if reference considered, regardless of whether citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.